

# 74LCX240SJ Datasheet



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DiGi Electronics Part Number 74LCX240SJ-DG

Manufacturer onsemi

Manufacturer Product Number 74LCX240SJ

Description IC BUFFER INVERT 3.6V 20SOP

Detailed Description Buffer, Inverting 2 Element 4 Bit per Element 3-Stat

e Output 20-SOP



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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### **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
74LCX240SJ	onsemi
Series:	Product Status:
74LCX	Obsolete
Logic Type:	Number of Elements:
Buffer, Inverting	2
Number of Bits per Element:	Input Type:
4	
Output Type:	Current - Output High, Low:
3-State	24mA, 24mA
Voltage - Supply:	Operating Temperature:
2V ~ 3.6V	-40°C ~ 85°C (TA)
Mounting Type:	Package / Case:
Surface Mount	20-SOIC (0.209", 5.30mm Width)
Supplier Device Package:	Base Product Number:
20-SOP	74LCX240

### **Environmental & Export classification**

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



## Low Voltage Octal Buffer/Line Driver with 5 V Tolerant Inputs and Outputs

### 74LCX240

The LCX240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver. The device is designed for low voltage  $V_{\rm CC}$  applications with capability of interfacing to a 5 V signal environment.

The LCX240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

#### **Features**

- 5 V Tolerant Inputs and Outputs
- 1.65 V-5.5 V V<sub>CC</sub> Specifications Provided
- 6.5 ns t<sub>PD</sub> Max. (V<sub>CC</sub> 3.3 V), 10 μα I<sub>CC</sub> Max.
- Power-down High Impedance Inputs and Outputs
- Supports Live Insertion/Withdrawal<sup>1</sup>
- $\pm 24$  mA Output Drive ( $V_{CC} = 3.0 \text{ V}$ )
- Implements Proprietary Noise/EMI Reduction Circuitry
- Latch-up Performance Exceeds 100 mA
- ESD Performance:
  - ♦ Human Body Model >2000 V
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

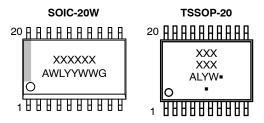




SOIC-20W CASE 751BJ

TSSOP-20 CASE 948AQ

#### **MARKING DIAGRAMS**



XXXXXX = Specific Device Code

A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year

WW, W = Work Week
G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information on page 7 of this data sheet.

<sup>1.</sup> To ensure the high-impedance state during power up or down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

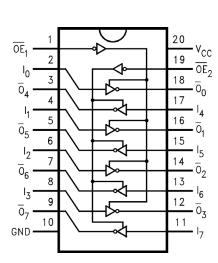


Figure 1. Connection Diagram



Pin Names	Description
$\overline{OE}_1$ , $\overline{OE}_2$	3-STATE Output Enable Inputs
I <sub>0</sub> –I <sub>7</sub>	Inputs
$\overline{O}_0 - \overline{O}_7$	Outputs

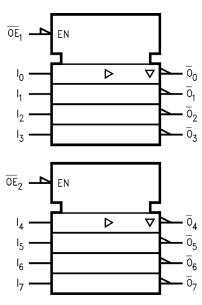


Figure 2. Logic Diagram

#### **TRUTH TABLE**

Inputs		Outputs
ŌE <sub>1</sub>	l <sub>n</sub>	(Pins 12, 14, 16, 18)
L	L	Н
L	Н	L
Н	Х	Z

OE <sub>2</sub>	I <sub>n</sub>	(Pins 3, 5, 7, 9)
L	L	Н
L	Н	L
Н	Х	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
VI	DC Input Voltage (Note 1)		-0.5 to +6.5	V
Vo	DC Output Voltage (Note 1)	Active-Mode (High or Low State) Tri-State Mode Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> +0.5 -0.5 to +6.5 -0.5 to +6.5	٧
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-50	mA
Io	DC Output Source/Sink Current		±50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pi	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
TL	Lead Temperature, 1 mm from Case for 10 secs	260	°C	
T <sub>J</sub>	Junction Temperature Under Bias		+150	°C
θЈА	Thermal Resistance (Note 2)	96 99 150	°C/W	
P <sub>D</sub>	Power Dissipation in Still Air	1302 1256 833	mW	
MSL	Moisture Sensitivity	Level 3 Level 1	-	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	_
V <sub>ESD</sub>	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>O</sub> absolute maximum rating must be observed.

- 2. Measured with minimum pad spacing on an FR4 board, using 76 mm-by-114 mm, 2-ounce copper trace no air flow per JESD51-7.
- 3. HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A.

#### **RECOMMENDED OPERATING CONDITIONS (Note 4)**

Symbol	Pa	rameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Digital Input Voltage		0	5.5	V
Vo	Output Voltage	Active Mode (High or Low State) Tri-State Mode Power Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 5.5 5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise or Fall Rate	$\begin{array}{c} V_{CC} = 1.65 \text{ V to } 1.95 \text{ V} \\ V_{CC} = 2.3 \text{ V to } 2.7 \text{ V} \\ V_{IN} \text{ from } 0.8 \text{ V to } 2.0 \text{ V, } V_{CC} = 3.0 \text{ V} \\ V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{array}$	0 0 0	20 20 10 5	nS/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

4. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V<sub>CC</sub>). Unused outputs must be left open.

#### DC ELECTRICAL CHARACTERISTICS

				T <sub>A</sub> = -40 °C to +85 °C		T <sub>A</sub> = -40 °C	to +125 °C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level		1.65 to 1.95	0.65 x V <sub>CC</sub>		0.65 x V <sub>CC</sub>		٧
	Input Voltage		2.3 to 2.7	1.7		1.7		1
			2.7 to 3.6	2.0		2.0		1
			4.5 to 5.5	0.7 x V <sub>CC</sub>		0.7 x V <sub>CC</sub>		1
V <sub>IL</sub>	Low-Level		1.65 to 1.95		0.35 x V <sub>CC</sub>		0.35 x V <sub>CC</sub>	V
	Input Voltage		2.3 to 2.7		0.7		0.7	
			2.7 to 3.6		0.8		0.8	1
			4.5 to 5.5		0.3 x V <sub>CC</sub>		0.3 x V <sub>CC</sub>	1
V <sub>OH</sub>	High-Level	$V_I = V_{IH}$ or $V_{IL}$	•	•	•	•	•	V
	Output Voltage	I <sub>OH</sub> = -100 μA	1.65 to 5.5	V <sub>CC</sub> - 0.1	_	V <sub>CC</sub> - 0.1	_	1
		I <sub>OH</sub> = -4 mA	1.65	1.2	-	1.2	_	1
		I <sub>OH</sub> = -8 mA	2.3	1.8	-	1.8	_	1
		I <sub>OH</sub> = -12 mA	2.7	2.2	-	2.2	_	1
		I <sub>OH</sub> = -16 mA	3.0	2.4	-	2.4	_	1
		I <sub>OH</sub> = -24 mA	3.0	2.2	-	2.2	_	1
		I <sub>OH</sub> = -32 mA	4.5	3.8		3.8		1
V <sub>OL</sub>	Low-Level	$V_I = V_{IH}$ or $V_{IL}$	•					٧
	Output Voltage	I <sub>OL</sub> = 100 μA	1.65 to 5.5	-	0.1	-	0.1	1
		I <sub>OL</sub> = 4 mA	1.65	-	0.45	-	0.45	1
		I <sub>OL</sub> = 8 mA	2.3	-	0.6	-	0.6	1
		I <sub>OL</sub> = 12 mA	2.7	-	0.4	-	0.4	1
		I <sub>OL</sub> = 16 mA	3.0	-	0.4	-	0.4	1
		I <sub>OL</sub> = 24 mA	3.0	-	0.55	-	0.55	1
		I <sub>OL</sub> = 32 mA	4.5		0.6		0.6	1
lį	Input Leakage Current	V <sub>I</sub> = 0 to 5.5 V	3.6	-	±5.0	-	±5.0	μΑ
I <sub>OZ</sub>	3-State Output Leakage Current	$V_I = V_{IH}$ or $V_{IL}$ , $V_O = 0$ V to 5.5 V	3.6	-	±5.0	-	±5.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>I</sub> = 5.5 V or V <sub>O</sub> = 5.5 V	0	-	10	-	10	μΑ
I <sub>CC</sub>	Quiescent	V <sub>I</sub> = 5.5 V or GND	2.3 to 3.6	-	10	-	10	μΑ
	Supply Current	3.6 V ≤ V <sub>I</sub> , V <sub>O</sub> ≤ 5.5 V (Note 5)			±10.0		±10.0	
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6 V$	2.3 to 3.6	-	500	-	500	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Outputs disabled or 3-STATE only.

#### **AC ELECTRICAL CHARACTERISTICS**

				T <sub>A</sub> = -40 °	C to +85 °C	T <sub>A</sub> = -40 °C	C to +125 °C	
Symbol	Parameter	Test Condition	V <sub>CC</sub> (V)	Min	Max	Min	Max	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, D	See Figures	1.65 to 1.95	-	10.3	-	10.3	ns
	to O	3 and 4	2.3 to 2.7	-	7.8	-	7.8	
			2.7	-	7.5	-	7.5	
			3.0 to 3.6	-	6.5	-	6.5	
			4.5 to 5.5	-	5.9	-	5.9	
t <sub>PZH</sub> , t <sub>PZL</sub>	Output Enable Time, OE to O	See Figures	1.65 to 1.95	-	13.0	-	13.0	ns
	OE to U	3 and 4	2.3 to 2.7	=	10.0	=	10.0	
			2.7	-	9.0	-	9.0	
			3.0 to 3.6	=	8.0	=	8.0	
			4.5 to 5.5	=	7.3	=	7.3	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Output Disable Time, OE to O	See Figures 3 and 4	1.65 to 1.95	=	11.0	=	11.0	ns
	OE to U	3 and 4	2.3 to 2.7	=	8.4	=	8.4	
			2.7	=	8.0	=	8.0	
			3.0 to 3.6	=	7.0	=	7.0	
			4.5 to 5.5	=	6.0	=	6.0	
toshL,	Output to Output		1.65 to 1.95	-	-	-	=	ns
toslh	H Skew (Note 6)		2.3 to 2.7	-	-	-	=	
			2.7	-	-	-	=	
			3.0 to 3.6	-	1.0	-	1.0	

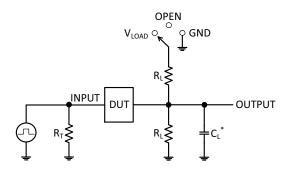
<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> x V<sub>CC</sub> x f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>in</sub> + I<sub>CC</sub> x V<sub>CC</sub>.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

			v <sub>cc</sub>	T <sub>A</sub> = +25 °C	
Symbol	Characteristic	Condition	(V)	Тур	Unit
V <sub>OLP</sub>	Quiet Output	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
	Dynamic Peak V <sub>OL</sub>	C <sub>L</sub> = 30 pF, V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	2.5	0.6	
V <sub>OLV</sub>	Quiet Output	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	-0.8	V
	Dynamic Valley V <sub>OL</sub>	C <sub>L</sub> = 30 pF, V <sub>IH</sub> = 2.5 V, V <sub>IL</sub> = 0 V	2.25	-0.6	

#### **CAPACITIVE CHARACTERISTICS**

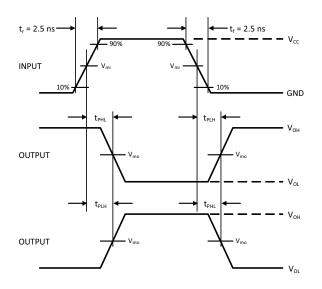
Symbol	Parameter	Condition	Тур	Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$	7	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10 MHz, $V_{CC}$ = 3.3 V, $V_I$ = 0 V or $V_{CC}$	25	pF

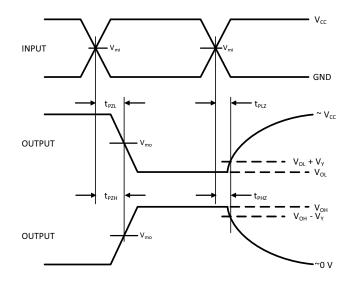


Test	Switch Position
t <sub>PLH</sub> / t <sub>PHL</sub>	Open
t <sub>PLZ</sub> / t <sub>PZL</sub>	$V_{LOAD}$
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND

\* $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ ) f = 1 MHz

Figure 3. Test Circuit





V <sub>CC</sub> , V	$R_L, \Omega$	C <sub>L</sub> , pF	V <sub>LOAD</sub>	V <sub>mi</sub> , V	V <sub>mo</sub> , V	V <sub>Y</sub> , V
1.65 to 1.95	500	30	2 x V <sub>CC</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.3 to 2.7	500	30	2 x V <sub>CC</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.15
2.7	500	50	6 V	1.5	V <sub>CC</sub> /2	0.3
3.0 to 3.6	500	50	6 V	1.5	V <sub>CC</sub> /2	0.3
4.5 to 4.5	500	50	2 x V <sub>CC</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

Figure 4. Switching Waveforms

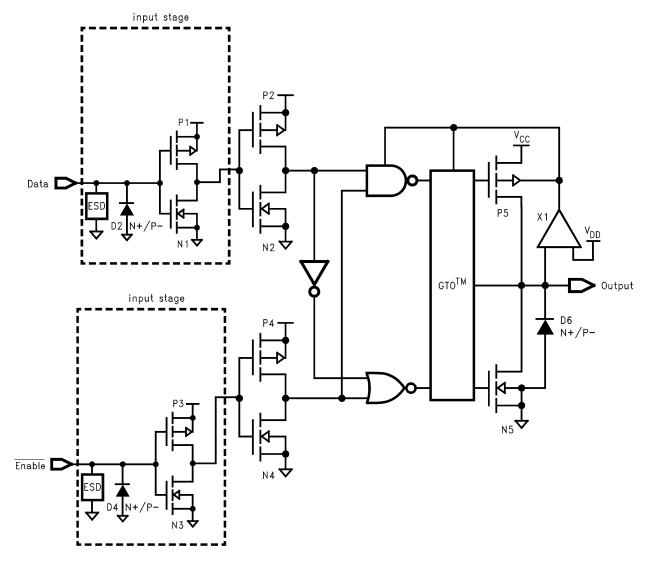


Figure 5. Schematic Diagram (Generic for LCX Family)

#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping <sup>†</sup>
74LCX240MTCX	LCX 240	TSSOP-20 (Pb-Free)	2500 / Tape & Reel

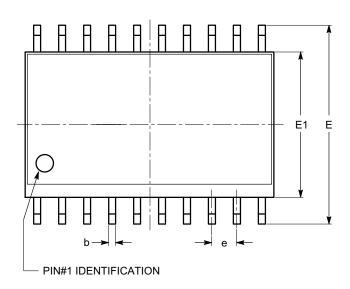
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

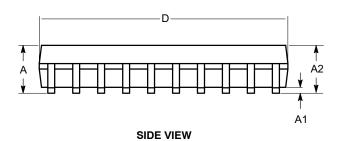
SOIC-20, 300 mils CASE 751BJ ISSUE O

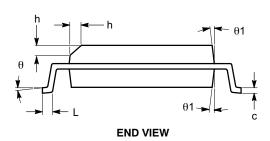
**DATE 19 DEC 2008** 



SYMBOL	MIN	NOM	MAX
Α	2.36	2.49	2.64
A1	0.10		0.30
A2	2.05		2.55
b	0.31	0.41	0.51
С	0.20	0.27	0.33
D	12.60	12.80	13.00
Е	10.01	10.30	10.64
E1	7.40	7.50	7.60
е		1.27 BSC	
h	0.25		0.75
L	0.40	0.81	1.27
θ	0°		8°
θ1	5°		15°

**TOP VIEW** 





#### Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MS-013.

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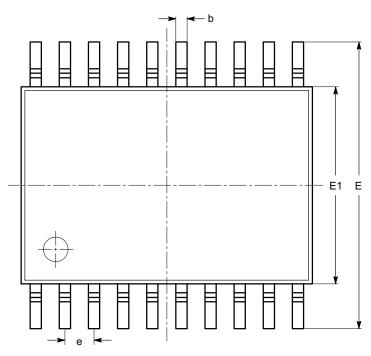


### MECHANICAL CASE OUTLINE

**PACKAGE DIMENSIONS** 

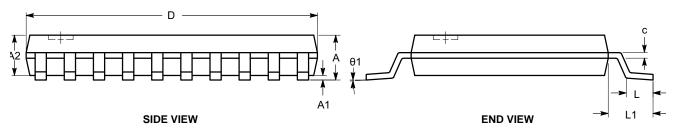
TSSOP20, 4.4x6.5 CASE 948AQ ISSUE A

**DATE 19 MAR 2009** 



SYMBOL	MIN	NOM	MAX
А			1.20
A1	0.05		0.15
A2	0.80		1.05
b	0.19		0.30
С	0.09		0.20
D	6.40	6.50	6.60
Е	6.30	6.40	6.50
E1	4.30	4.40	4.50
е		0.65 BSC	
L	0.45	0.60	0.75
L1		1.00 REF	
θ	0°		8°

#### **TOP VIEW**



#### Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-153.

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